Electronic Supplementary Information for

Rapid structural discrimination of IgG antibodies by multicharge-state collision-induced unfolding

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Fig. S2. IM-MS drift-time distributions of (A) $IgG1\kappa$, (B) $IgG2\kappa$, (C) $IgG3\kappa$, and (D) $IgG4\kappa$ at the charge state of 22+ with collision energy ranging from 10 V to 200 V. Each IM-MS spectrum was normalized for different collision energies.



Fig. S3. IM-MS drift-time distributions of (A) $IgG1\kappa$, (B) $IgG2\kappa$, (C) $IgG3\kappa$, and (D) $IgG4\kappa$ at the charge state of 24+ with collision energy ranging from 10 V to 200 V. Each IM-MS spectrum was normalized for different collision energies.



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Fig. S5. CIU fingerprints of IgG2κ at the charge state of (A) 21+, (B) 22+, (C) 23+, (D) 24+, and (E) 25+. CIU difference plots of (F) 21+ vs. 22+, (G) 21+ vs. 23+, (H) 21+ vs. 24+, (I) 21+ vs. 25+, (J) 22+ vs. 23+, (K) 22+ vs. 24+, (L) 22+ vs. 25+, (M) 23+ vs. 24+, (N) 23+ vs. 25+, and (O) 24+ vs. 25+.



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Fig. S8. CIU fingerprints of (A) IgG1 κ , (B) IgG2 κ , (C) IgG3 κ , and (D) IgG4 κ at the charge state of 21+. CIU difference plots of (E) IgG1 κ vs. IgG2 κ , (F) IgG1 κ vs. IgG3 κ , (G) IgG1 κ vs. IgG4 κ , (H) IgG2 κ vs. IgG3 κ , (I) IgG2 κ vs. IgG4 κ , (J) IgG3 κ vs. IgG4 κ .



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Fig. S10. CIU fingerprints of (A) IgG1 κ , (B) IgG2 κ , (C) IgG3 κ , and (D) IgG4 κ at the charge state of 24+. CIU difference plots of (E) IgG1 κ vs. IgG2 κ , (F) IgG1 κ vs. IgG3 κ , (G) IgG1 κ vs. IgG4 κ , (H) IgG2 κ vs. IgG3 κ , (I) IgG2 κ vs. IgG4 κ , (J) IgG3 κ vs. IgG4 κ .



Fig. S11. CIU fingerprints of (A) IgG1 κ , (B) IgG2 κ , (C) IgG3 κ , and (D) IgG4 κ at the charge state of 25+. CIU difference plots of (E) IgG1 κ vs. IgG2 κ , (F) IgG1 κ vs. IgG3 κ , (G) IgG1 κ vs. IgG4 κ , (H) IgG2 κ vs. IgG3 κ , (I) IgG2 κ vs. IgG4 κ , (J) IgG3 κ vs. IgG4 κ .

Ion source	Typical Parameter
Capillary Voltage (kV)	1.2-1.6
Sampling Cone (V)	40
Source Offset (V)	80
Temperature (°C)	30
Cone Gas (L/h)	0
Nano Flow gas (L/h)	0
Purge Gas (L/h)	0
Trap DC	
Entrance (V)	5.0
Bias (V)	50.0
Trap DC (V)	-2.0
Exit (V)	20.0
IMS	
Entrance (V)	10.0
Helium Cell DC (V)	50.0
Helium Exit (V)	-40.0
Bias (V)	3.0
Exit (V)	2.0
Transfer DC	
Entrance (V)	15.0
Exit (V)	15.0
TriWave	
Wave Velocity (m/s)	250.0
Wave Height (V)	2.0
IMS	

Table S1. The detailed instrumental parameters of Synapt G2-Si HDMS

Wave Velocity (m/s)	600.0
Wave Height (V)	40.0
Transfer	
Wave Velocity (m/s)	175.0
Wave Height (V)	12.0
StepWave 1	
Wave Velocity (m/s)	300.0
Wave Height (V)	10.0
StepWave 2	
Wave Velocity (m/s)	300.0
Wave Height (V)	0.0
StepWave DC	
StepWave 2 Offset	60.0
Diff Aperture 1	10.0
Diff Aperture 2	10.0
Source Ion Guide	
Wave Velocity (m/s)	300.0
Wave Height (V)	0.0
RF Setting	
StepWave (V)	300.0
Ion Source (V)	350.0
Gas Control	
Trap (V)	2.0
Helium Cell (L/h)	200.0
IMS (V)	80.0
MS Profile Type	Auto Profile
Mass 1	1.25 Ma (Low m/z limit)
Dwell Time 1	25%

Ramp Time 1	75%
Mass 2	0.17 Mb (High m/z limit)

	21+	22+	23+	24+	25+
IgG1ĸ	73.8 V	68.5 V	66.5 V	60.4 V	54.4 V
		145.0	134.5 V	103.3 V	82.5 V
					168.5 V
IgG2κ	69.7 V	66.8 V	62.6 V	56.4 V	52.7 V
		155.1 V	74.9 V	74.2 V	72.1 V
			132.5 V	114.5 V	101.7 V
			163.2 V	120.0 V	97.6 V
IgG3ĸ	77.9 V	76.9 V	74.9 V	70.6 V	64.8 V
	136.0 V	122.4 V	110.2 V	94.8 V	83.1 V
					169.8 V
IgG4ĸ	76.8 V	65.1 V	62.5 V	57.5 V	54.5 V
	150.1 V	123.8 V	92.2 V	87.5 V	82.1 V
					179.3 V

 Table S2. The transition voltage required for conformation transition.

	21+	22+	23+	24+	25+
IgG1κ vs. IgG2κ	12.24	15.05	19.45	20.32	23.19
IgG1κ vs. IgG3κ	31.37	36.19	34.73	31.76	32.75
IgG1κ vs. IgG4κ	22.28	25.43	28.67	17.57	18.74
IgG2κ vs. IgG3κ	29.61	35.09	37.05	34.67	29.81
IgG2κ vs. IgG4κ	24.14	28.68	32.34	22.84	25.43
IgG3κ vs. IgG4κ	30.81	27.69	25.74	28.26	28.21

 Table S3. RMSD values acquired from IgG subtypes with different charge states.